

ON Semiconductor®

FPF2281

Over-Voltage Protection Load Switch

Features

- Surge Protection
 - IEC 61000-4-5: > 100 V
- Over-Voltage Protection (OVP)
- Over-Temperature Protection (OTP)
- ESD Protection
 - Human Body Model (HBM): > 3.5 kV
 - Charged Device Model (CDM): > 2 kV
 - IEC 61000-4-2 Air Discharge: > 15 kV
 - IEC 61000-4-2 Contact Discharge: > 8 kV

Applications

- Mobile Handsets and Tablets
- Portable Media Players
- MP3 Players

Description

The FPF2281 features a low-RoN internal FET and an operating range of 2.5 V_{DC} to 25 V_{DC} (absolute maximum of 29 V_{DC}). An internal clamp is capable of shunting surge voltages >100 V, protecting downstream components and enhancing system robustness. The FPF2281 features over-voltage protection that powers down the internal FET if the input voltage exceeds the OVP threshold. The OVP threshold is adjustable with optional external resistors. Over-temperature protection also powers down the device at 130°C (typical). Exceptionally low off-state current (<1 μ A maximum) facilitates compliance with standby power requirements.

The FPF2281 is available in a fully "green" compliant 1.3 mm × 1.8 mm Wafer-Level Chip-Scale Package (WLCSP) with backside laminate.

Related Resources

http://www.onsemi.com/

Ordering Information

Part Number	Part Number Operating Temperature Range		Package	Packing Method	
FPF2281BUCX-F130	-40°C − 85°C	HE	12-Ball, 0.4 mm Pitch WLCSP	Tape & Reel	

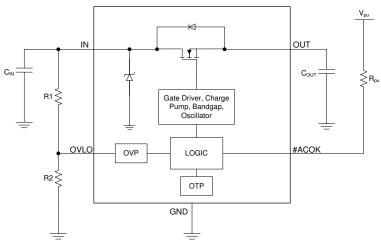
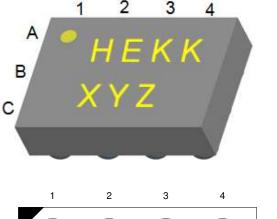
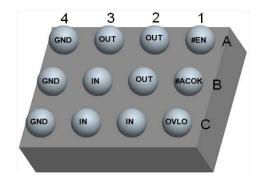
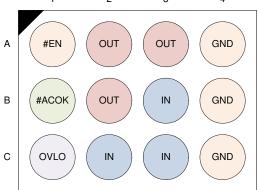


Figure 1. Functional Block Diagram

Pin Configuration







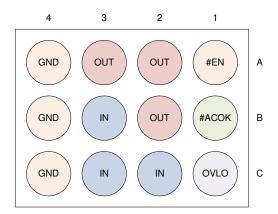


Figure 2. Pin Configuration (Top View)

Figure 3. Pin Configuration (Bottom View)

Pin Definitions

Name	Bump	Туре	Description				
IN	B3, C2, C3	Input/Supply	Switch Input and Device Supply				
OUT	A2, A3, B2	Output	Sw itch Output to Load				
#ACOK	B1	Output	Pow er Good		$V_{IN} < V_{IN_min} \text{ or } V_{IN} \ge V_{OVLO}$		
#AOOK	ום	Output	1 ow er dood	0	Voltage Stable		
#EN	A1	Input	Device Enable (Active LOW)				
OVLO	C1	Input	Over-Voltage Lockout Adjustment Pin				
GND	A4, B4, C4	Supply	Device Ground				

Over-Voltage Lockout (OVLO) Calculation

OVLO can be set externally and override default OVP. By connecting an external resistor-driver to the OVLO pin. Equation (1) can produce the desired trip voltage and resistor values.

$$V_{IN_OLVO} = V_{OVLO_TH} \times [1 + R1/R2]$$
 (1)
 Recommended minimum R1 = 1 M Ω .

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Max.	Unit	
V _{IN}	V_IN to GND & V_IN to V_OUT = GND or Float		-0.3	29.0	V	
V _{OUT}	V_OUT to GND		-0.3	$V_{IN} + 0.3$	V	
V _{OVLO}	OVLO to GND		-0.3	25.0	V	
V#EN_ACOK	Maximum DC Voltage Allowed on #EN or ACOK Pin			6	V	
I _{IN}	Switch I/O Current (Continuous)			4.5	Α	
ЧN	Peak Switch I/O Current (10 ms)			9	Α	
tP _D	Total Power Dissipation at T _A = 25°C			1.48	W	
T _{STG}	Storage Temperature Range			+150	°C	
TJ	Maximum Junction Temperature			+150	°C	
TL	Lead Temperature (Soldering, 10 Seconds)		+260	°C		
ΘJA	Thermal Resistance, Junction-to-Ambient ⁽¹⁾ (1-in. ² Pad of 2-oz. Copper)			84.1	°C/W	
	IEC 61000-4-2 System ESD	Air Gap	15.0			
F0D		Contact	8.0		147	
ESD	Human Body Model, ANSI / ESDA / JEDEC JS-001-2012	All Pins	3.5		kV	
	Charged Device Model, JEDEC JESD22-C101 All Pins		2.0			
Surge	IEC 61000-4-5, Surge Protection V _{IN}				V	

Note:

1. Measured using 2S2P JEDEC std. PCB.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Max.	Unit
V _{IN}	Supply Voltage	2.5	25.0	V
TA	Operating Temperature		+85	ōC

Electrical Characteristics

 $T_A = -40^{\circ} C$ to $85^{\circ} C$ unless otherwise indicated. Typical values are $V_{IN} = 5.0 \text{ V}$, $I_{IN} \leq 3 \text{ A}$, $C_{IN} = 0.1 \text{ }\mu\text{F}$ and $T_A = 25^{\circ} C$.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit		
V _{IN_CLAMP}	Input Clamping Voltage	$I_{IN} = 10 \text{ mA}$		35		V		
la	Input Quiescent Current	V _{IN} = 5 V, #EN = 0 V		58	100	μΑ		
l _{IN_Q}	OVLO Supply Current	V _{OVLO} = 3 V, V _{IN} = 5 V, V _{OUT} = 0 V		52	100	μΑ		
V _{IN OVLO}	Internal Over-Voltage Trip Level	V _{IN} Rising	13.6	14.0	14.4	V		
V IN_OVLO	lillemai Over-vollage mp Level	V _{IN} Falling	13.0			V		
V _{OVLO_TH}	OVLO Set Threshold	$V_{IN} = 2.5 \text{ V to } V_{OVLO}$	1.12	1.20	1.24			
V _{OVLO_RNG}	Adjustable OVLO Threshold Range	V _{IN} = 2.5 V to V _{OVLO}	4		25	V		
V _{OVLO_SELECT}	External OVLO Select Threshold			0.30	0.28	V		
V _{UVLO}		VIN Rising, T _{A=} -40 to 85°C		2.25	2.4	V		
V UVLO	Under-Voltage Trip Level	VIN Falling, T _A = -40 to 85°C		1.95	2.1	V		
Ron	Resistance from V _{IN} to V _{OUT}	$V_{IN} = 5 \text{ V}, I_{OUT} = 1 \text{ A}, T_A = 25^{\circ}\text{C}$		30	39	mΩ		
Соит	OUT Load Capacitance ⁽²⁾	V _{IN} = 5 V			1000	μF		
lolvo	OVLO Input Leakage Current	V _{OVLO} = V _{OVLO} _TH	-100		100	nA		
T _{SDN}	Thermal Shutdow n ⁽²⁾			130		°C		
T _{SDN_HYS}	Thermal Shutdown Hysteresis (2)			20		°C		
Digital Signa	als			•				
V _{OL}	#ACOK Output Low Voltage	I _{SINK} = 1 mA			0.4	V		
VIH_#EN	Enable HIGH Voltage	$V_{IN} = 2.5 \text{ V to } V_{OVLO}$	1.2			V		
VIL_#EN	Enable LOW Voltage	$V_{IN} = 2.5 \text{ V to } V_{OVLO}$			0.5	V		
lacok_leak	#ACOK Leakage Current	V _{ACOK} = 3 V, #ACOK Deasserted	-0.5		0.5	μΑ		
#EN_Leak	#EN Leakage Current	$V_{IN} = 5.0 \text{ V}, V_{OUT} = \text{Float}$	-1.0		1.0	μΑ		
Timing Char	Timing Characteristics							
tDEB	Debounce Time	Time from 2.5 V < V_{IN} < V_{IN_OVLO} to V_{OUT} = 0.1 × V_{IN}		15		ms		
tstart	Soft-Start Time	Time from $V_{IN} = V_{IN_min}$ to $0.2 \times \#A$ COK, $V_{IO} = 1.8$ V w ith 10 k Ω Pull-up Resistor		30		ms		
ton	Sw itch Turn-On Time	$\begin{aligned} R_L &= 100~\Omega,~C_L = 22~\mu F,~V_{OUT}\\ from~0.1~\times~V_{IN}~to~0.9~\times~V_{IN}, \end{aligned}$		2		ms		
toff	Sw itch Turn-Off Time ⁽²⁾	$\begin{aligned} R_L &= 100~\Omega,~C_L = 0~\mu\text{F},\\ V_{IN} &> V_{OVLO}\text{to}~V_{OUT} = 0.8~\times V_{IN} \end{aligned}$		125		ns		

Note:

2. Guaranteed by characterization and design.

Timing Diagrams

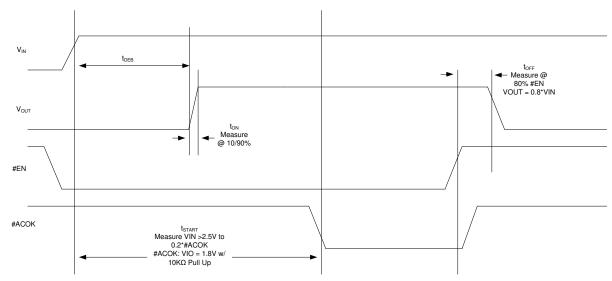


Figure 4. Timing for Power Up and Normal Operation

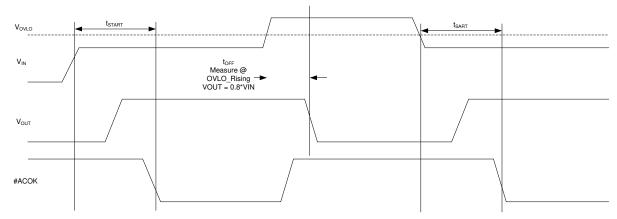


Figure 5. Timing for OVLO Trip

Product-Specific Dimensions

The table below provides information regarding the WLCSP package on the following page.

D	E	Х	Υ
1288 μm ±30 μm	1828 μm ±30 μm	314 μm ±18 μm	244 μm ±18 μm

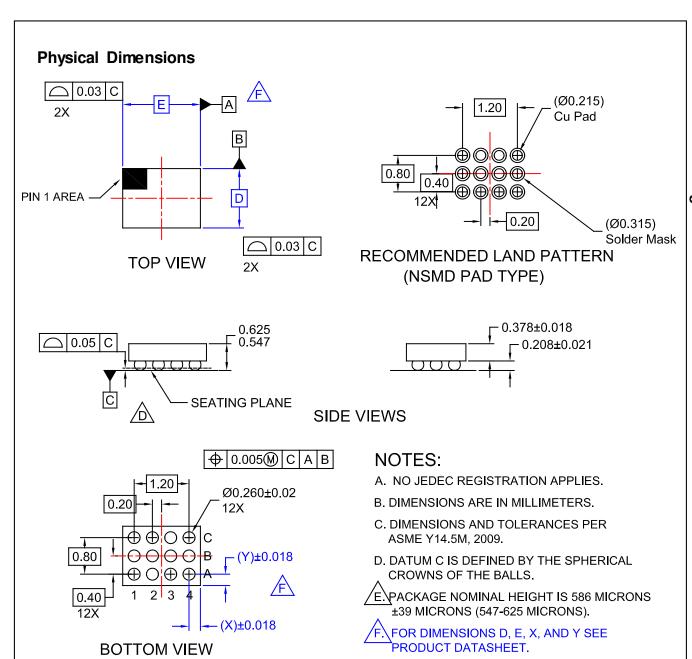


Figure 6. 12-Ball, 3x4 Array, 0.4 mm Pitch, Wafer-Level Chip-Scale Package (WLCSP)

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